Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	21141	magnetic near3 memory	USPAT	OR	OFF	2005/12/12 17:06
L2	2663	tmr	USPAT	OR	OFF	2005/12/12 17:06
L3	23310	1 or 2	USPAT	OR	OFF	2005/12/12 17:06
L4	860350	global or main	USPAT	OR	OFF	2005/12/12 17:06
L5	4530	bitline$1	USPAT	OR	OFF	2005/12/12 17:07
L6	337352	writ$3	USPAT	OR	OFF	2005/12/12 17:07
L7	222	4 near2 5	USPAT	OR	OFF	2005/12/12 17:07
L8	0	3 same 6 same 7	USPAT	OR	OFF	2005/12/12 17:08
L9	1	3 same 7	USPAT	OR	OFF	2005/12/12 17:10
L10	795370	resistance	USPAT	OR	OFF	2005/12/12 17:10
L11	725531	storage	USPAT	OR	OFF	2005/12/12 17:10
L12	1272701	parallel	USPAT	OR	OFF	2005/12/12 17:10
L13	327	10 with 11 with 12	USPAT	OR	OFF	2005/12/12 17:14
L14	12207	select$3 near2 transistor	USPAT	OR	OFF	2005/12/12 17:11
L15	1	13 with 14	USPAT	OR	OFF	2005/12/12 17:11
L16	40734	storage near2 (portion or element or cell)	USPAT	OR	OFF	2005/12/12 17:15
L17	352	magneto-resistance near2 (portion or element or cell)	USPAT	OR	OFF	2005/12/12 17:15
L18	242784	transistor	USPAT	OR	OFF	2005/12/12 17:15
L19	34	16 with 17	USPAT	OR	OFF	2005/12/12 17:15
L20	9	("20020055016" | "20040136231" | "5659499" | "5940319" | "5953248" | "5956267" | "5966012" | "5966323" | "6767655").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/12/12 17:19
L21	0	("6956765").URPN.	USPAT	OR	OFF	2005/12/12 17:21